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Standard Recovery Diodes, (Stud Version), 300 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	300 A					
Package	DO-9 (DO-205AB)					
Circuit configuration	Single					

FEATURES

- Wide current range
- High voltage rating up to 2500 V
- High surge current capabilities
- Stud cathode and stud anode version
- High resistance to acceleration
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	301	U(R)	UNITS			
PARAMETER	TEST CONDITIONS	160 TO 200	250	UNITS			
		330	300	A			
I _{F(AV)} T _C		120	120	°C			
I _{F(RMS)}		520	470	A			
1	50 Hz	8250	6050	٨			
IFSM	60 Hz	8640	6335	A			
l ² t	50 Hz	340	340 183				
1-1	60 Hz	311	167	kA ² s			
V _{RRM}	Range	1600 to 2000	2500	V			
TJ		-40 to +180	-40 to +180	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA					
VS-301U(R) VS-303U(R)	160	1600	1700						
VS-305U(R)	200	2000	2100	15					
VS-307U(R) VS-309U(R)	250	2500	2600						

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FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			301U(R)		UNITS	
FARAIVIETER	STIVIDOL		TEST CON		160 TO 200	250	UNITS	
Maximum average forward current		190° condu	ction. half sine w	10110	330	300	А	
at case temperature	I _{F(AV)}		ction, nan sine w	lave	120	120	°C	
Maximum RMS forward current	I _{F(RMS)}	DC at T _C = ⁻	115 °C (up to 20	00 V), T _C = 102 °C (2500 V)	520	470	А	
		t = 10 ms	No voltage		8250	6050		
Maximum peak, one cycle forward,	I =0.1	t = 8.3 ms	reapplied		8640	6335	А	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		6940	5090	kA ² s	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	7270	5330		
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	340	183		
		t = 8.3 ms	reapplied		311	167		
Maximum tion rusing		t = 10 ms	100 % V _{RRM}		241	129		
		t = 8.3 ms	reapplied		220	118		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10) ms, no voltage	reapplied	3400	1830	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	I _{F(AV)}), T _J = T _J maximum	0.77	0.90	v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			0.97	v	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.49	0.59	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)})$	0.49	0.55	11152			
Maximum forward voltage drop	V _{FM}	l _{pk} = 942 A, wave	$T_J = T_J maximul$	m, t _p = 10 ms sinusoidal	1.22	1.46	V	

SPECIAL SELECTION FORWARD VOLTAGE (T _j = 25 °C)								
DEVICE CLASSIFICATION	BAND	MIN.	MAX.	UNIT	TEST CONDITIONS			
VS-305U250P4 VS-307UA250P4 VS-305UR250P4 VS-307URA250P4	P4	1.31	1.40	V	1000 A _{pk}			

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction operative temperature range	ating	TJ		-40 to 180	°C		
Maximum storage temperature range		T _{Stg}		-40 to 200	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.14			
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, flat and greased	0.08	K/W		
Maximum allowed mounting torque			Not lubricated threads	37	N⋅m		
+0 -20 %			Lubricated threads	28	IN • III		
	301U			250 ± 5			
	303U			152 ± 5			
Weight	305U			177 ± 5	g		
	307U			197 ± 5	1		
	309U			160 ± 5			
Case style			See dimensions - link at the end of datasheet	DO-9 (DO	-205AB)		

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CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAF	R CONDUCTION	TEST CONDITIONS	UNITS		
CONDUCTION ANGLE	80 TO 200	250	80 TO 200	250	TEST CONDITIONS	UNITS		
180°	0.015	0.015	0.011	0.011		K/W		
120°	0.018	0.018	0.019	0.019				
90°	0.023	0.023	0.025	0.025	$T_J = T_J maximum$			
60°	0.034	0.034	0.035	0.035				
30°	0.056	0.056	0.057	0.057				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

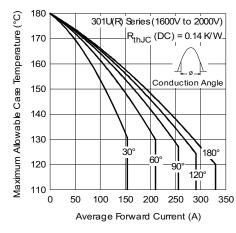


Fig. 1 - Current Ratings Characteristics

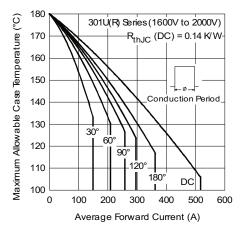


Fig. 1 - Current Ratings Characteristics

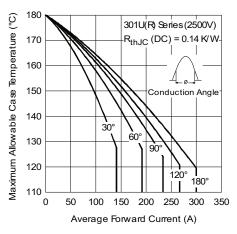


Fig. 2 - Current Ratings Characteristics

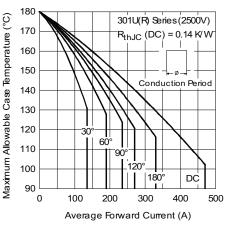
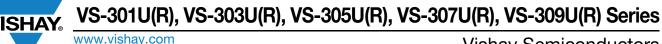


Fig. 3 - Current Ratings Characteristics

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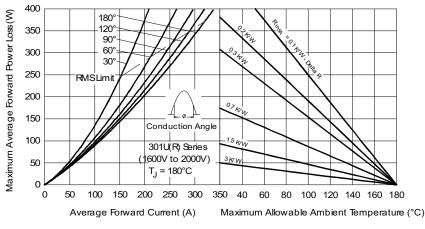


Fig. 4 - Forward Power Loss Characteristics

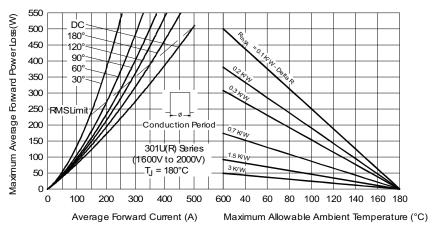
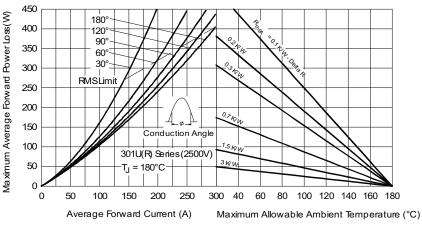
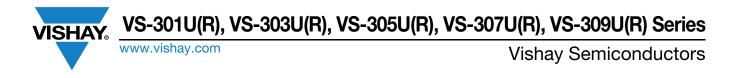


Fig. 5 - Forward Power Loss Characteristics





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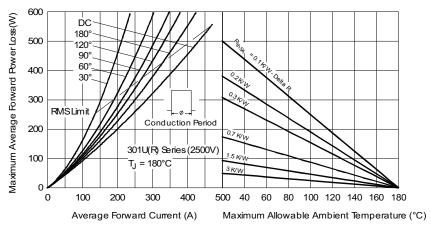


Fig. 7 - Forward Power Loss Characteristics

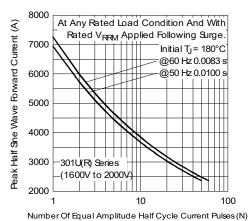


Fig. 8 - Maximum Non-Repetitive Surge Current

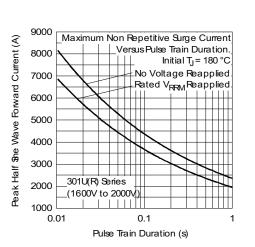


Fig. 9 - Maximum Non-Repetitive Surge Current

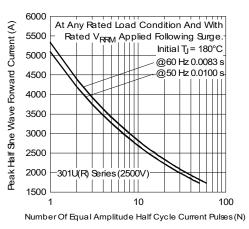


Fig. 10 - Maximum Non-Repetitive Surge Current

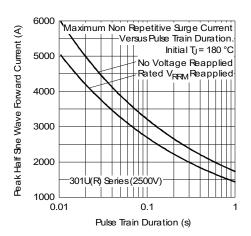


Fig. 11 - Maximum Non-Repetitive Surge Current

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VS-301U(R), VS-303U(R), VS-305U(R), VS-307U(R), VS-309U(R) Series ISHA www.vishay.com

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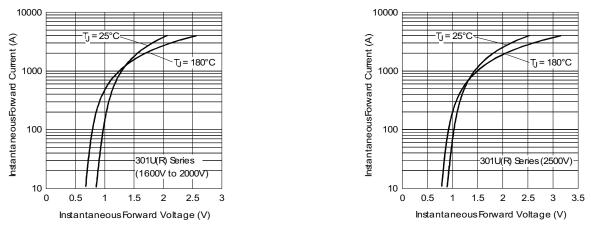


Fig. 12 - Forward Voltage Drop Characteristics

Fig. 13 - Forward Voltage Drop Characteristics

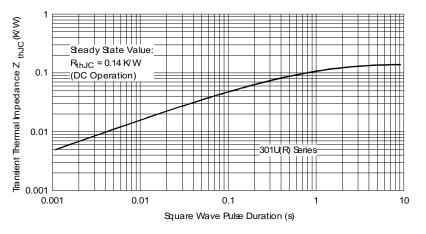


Fig. 14 - Thermal Impedance ZthJC Characteristic

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ORDERING INFORMATION TABLE

Device code	vs-	30	1	U	Α	250	Р4	
	1	2	3	4	5	6	7	
	1 -	Vish	nay Sem	niconduc	tors pro	duct		
	2 -	30 =	essent	ial part r	number			
	3 -	• 1 :	= standa	ard devi	ce			
		• 3 :	= top thi	readed v	version			
		 5 = type for rotating application with top threaded version 3/8 16UNC-2A 						
		• 7 :	 7 = type for rotating application with flexible lead 					
		• 9 :	 9 = type for rotating application with top threaded version 3/8 24UNF 					
	4 -	 U = stud normal polarity (cathode to stud) 						
		• UI	R = stud	l reverse	e polarity	/ (anode	e to stud)
	5.	- A =	maximu	ım leaka	ge sele	ction I _{RE}	ам = 2 m	nA, T _J = 25
	6 -				-			-
	7		Voltage code x 10 = V_{RRM} (see Voltage Ratings table) Refer special selection table for applicable parts					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95337						

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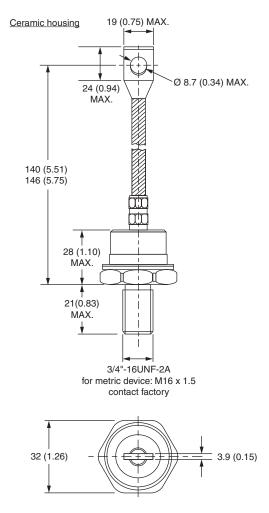
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DO-205AB (DO-9), B-60, B-61, B-41, B-40 for 301U(R), 307U(R), 305U(R) and 309U(R) Series

DIMENSIONS FOR 301U(R) SERIES - DO-205AB (DO-9) in millimeters (inches)

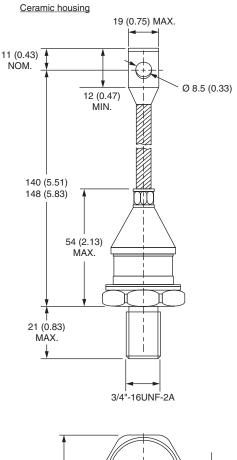


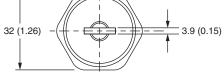
Outline Dimensions

Vishay Semiconductors DO-205AB (DO-9), B-60, B-61, B-41, B-40 for 301U(R), 307U(R), 305U(R) and 309U(R) Series



DIMENSIONS FOR 307U(R) SERIES - B-60 in millimeters (inches)





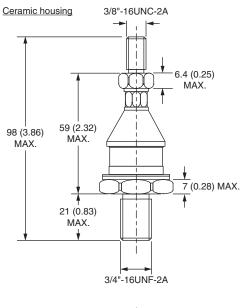
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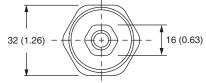
Outline Dimensions



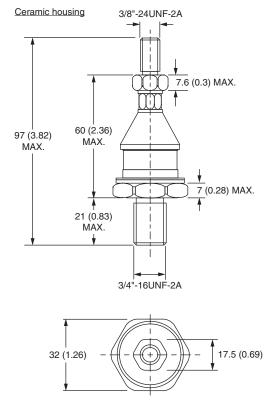
DO-205AB (DO-9), B-60, B-61, B-41, B-40 for Vishay Semiconductors 301U(R), 307U(R), 305U(R) and 309U(R) Series

DIMENSIONS FOR 305U(R) SERIES - B-61 in millimeters (inches)





DIMENSIONS FOR 309U(R) SERIES - B-41 in millimeters (inches)



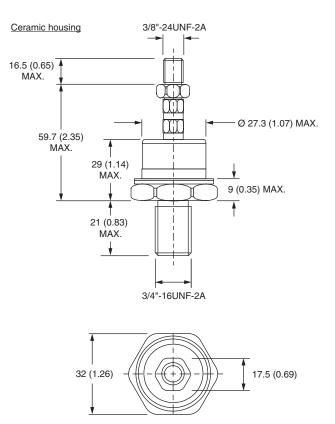
Document Number: 95337 Revision: 22-Jul-08

Outline Dimensions



Vishay Semiconductors DO-205AB (DO-9), B-60, B-61, B-41, B-40 for 301U(R), 307U(R), 305U(R) and 309U(R) Series

DIMENSIONS FOR 303U(R) SERIES - B-40 in millimeters (inches)



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